

GEETHANJALI INSTITUTE OF SCIENCE AND TECHNOLOGY (AUTONOMOUS) NELLORE – 524137 (A.P) INDIA

B.TECH Electrical and Electronics Engineering Course Structure (RG22)

Semester - 2 (Theory-5, Lab-3)									
SI.	Categor	Course	Cour	Hou	Credit				
N	У	Code		-				S C	
1	DOO	22 4 0 0 0 2 5	Differential La	motions		l	P	C	
	BSC	22A00021	andVector Cal	culus	3	0	0	3	
2	BSC	22A0003T	Applied Physic	cs	3	0	0	3	
3	HSC	22A0013T	Communicativ	e English	3	0	0	3	
4	ESC	22A0401T	Electronic Dev	3	0	0	3		
5	ESC	22A0302T	Engineering D	1	0	4	3		
6	HSC (Lab)	22A0014P	Communicativ	e English Lab	0	0	3	1.5	
7	BSC (Lab)	22A0008P	Applied Physic	0	0	3	1.5		
8	ESC (Lab)	22A0402P	Electronic Dev CircuitsLab	vices &	0	0	3	1.5	
				Total 19.5 credits				19.5	
		Category		Credits					
Ba	sic Science	Course (BSC)				7.5			
Eng	gineering Sc	(ESC)	7.5						
Hu	manities and	l Social Scienc	e Course		2	4.5			
(H3	SC)								
Total			19.5						

HoD

Dean of Academics

Principal

Differential Equations & Vector Calculus							
Course Code	L:T:P:S	Credits	Exam marks	Exam Duration	Course Type		
22A0002T	3:0:0:0	3	CIE:30 SEE:70	3 Hours	BSC		
Course Objec	ctives:	<u> </u>		I	I		
To enlighten the	he learners in	the concept o	f differential equa	tions and mult	tivariable		
calculus, to fu	rnishthe learn	ers with basi	c concepts and te	echniques at p	lus two level to		
lead them into	advanced lev	vel by handlir	ng various real wo	rld application	IS.		
Syllabus	Lincon D	ifforential F	austions of IT:-1	on Ondon	1 otal Hours:45		
Umt - 1	(Constan	t Coefficient	quations of filge	iei Oruer	7 1115		
Definitions, he	omogenous ar	nd non-homo	genous, complime	entary function	n, general solution,		
particular integ	gral, Wronske	an, method o	f variation of para	meters. Simul	taneous linear		
equations, Ap	plications to L	-C-R Circuit	problems and Ma	ass spring syst	em.		
Unit - II	Partial D	ifferential E	quations		9 Hrs		
Introduction a	nd formation of	of Partial Diff	ferential Equation	s by elimination	on of arbitrary		
constants	1	tions of f			2		
and arbitrary f	unctions, solu	uons of first	order equations us	sing Lagrange	s method. Non		
		і — туре I, II,	111, 1 V.		9 Hrs		
	Applicati	ions of Parti	al Differential Ec	quations	7 1115		
Classification	of PDE, m	ethod of sep	aration of varia	bles for seco	ond order equations.		
Applications of	of Partial Dif	ferential Equ	ations: One dime	ensional Wave	e equation (Without		
Derivation), S	Solutions one	Dimensional	l Wave equation	by the meth	od of separation of		
variables							
and related Pro	oblems.	100					
Unit - IV	Vector D	itterentiation	n on operator del d	al applica ta	9 Hrs		
functions-Grad	dient del appli	ed to vector r	or operator del, d	er applies to s	Curl vector		
identities.	aioni, uoi appii		Sant runchons-DI	, ergenee and v			
Unit - V	Vector In	ntegration			9 Hrs		
Line integral-c	circulation-wo	rk done, surfa	ace integral-flux,	Green's theore	em in the plane		
(without proof	f), Stoke's the	orem (withou	t proof), volume i	integral, Diver	gence theorem		
(without proof	$\frac{1}{2}$ and applicat	ions of these t	theorems.				
On completion	nnes (UU): n of this cours	e student w	ill he able to				
\rightarrow Solve th	e linear differe	ential equation	ns with constant c	oefficients by	appropriate		
method	d.	1	•		11 · I ·····		
≻ Apply a	range of tech	niques to find	solutions of stand	dard partial dif	ferential		
equation	ons.						
➤ Calcify t	he PDE, learn	the application	ions of PDEs	. .			
\succ Apply d	el to Scalar an	d vector poin	t functions, illustr	rate the physic	al interpretation		
ofGrad	itent, Diverge	nce and Curl	Tance theorom in	avaluation of	double and tripla		
integra	lls.	es and Diverg	zence meorem m	evaluation of	uouble and triple		
Textbooks:	•						
1. B.S. Gre	ewal, Higher I	Engineering N	Aathematics, 44/e	, Khanna publ	ishers, 2017.		
2. Differen	tial Equations	& Vector Cal	lculus by T.K.V. I	yengar, B.Kris	shna Gandhi,		
S.Ranganathan	mand M.V.S.S	S.N.Prasad S.	Chand publicatio	n.			
Reference Bo	oks:	15	·				
1. Erwin K 2011	reyszig, Adva	inced Enginee	ering Mathematics	s, 10/e, John V	Viley & Sons,		
2. B.V.Ran	nana. "Higher	Engineering	Mathematics". M	c Graw Hill nu	ublishers.		
3. Engineer	ring Mathmati	c I & II, by T	.K.V. Iyengar, B.	Krishna Gandl	ni, S.Ranganatham		
andM.V.S.S.N	I.Prasad S. Ch	and publicati	on.		, 0		
		-					

Applied Physics (Common to ECE, EEE)							
Course Code	Course CodeL:T:P:SCreditsExam MarksExam DurationCourse Type						
22A0003T	3:0:0:0	3	CIE:30 SEE:70	3Н	BSC		
Prerequisite:	Student should	l know about f	fundamental and	basic principles	in physics		
		C	ourse Objective	es:			
This course wi	ill enable stude	ents to:					
➤ To make a	bridge betwee	en the physics	in school and en	gineering cours	ses.		
To impart t andpolarization	he knowledge n.	in basic conce	pts of the optical	phenomenon l	ike interference, diffraction		
To underst and highenergy engineering ap	and the mecha y applications, plications.	anisms of emi study of prop	ssion of light, th agation of light v	ne use of lasers wave through o	as light sourcesfor low ptical fibers along with		
To open ne magneticmater	w avenues of listication is a set of the set	cnowledge and plication in the	d understanding t e emerging micro	he basic concept o devices.	ots of dielectric and		
 Evolution of chargecarriers 	of band theory in semiconduc	to distinguish ctors.	materials, basic	concepts and tra	ansport phenomenon of		
To identify	the importanc	e of semicond	uctors in the func	ctioning of elect	ronic devices.		
To enlighte applications.	en the concepts	related to sup	erconductivity w	hich leads to th	eir fascinating		
To impart l	knowledge in b	basic concepts	ofelectromagnet	ic waves			
		Syllabus			Total Hours:48		
	U	nit - I Wave	Optics		10		
Interference- Principle of superposition – Interference of light – Types of Interference – Path difference – Phase difference – Conditions for sustained interference- Interference in thin films (Reflection Geometry) – Colors in thin films – Newton's Rings – Determination of wavelength and refractive index of liquid.							
Diffraction- Introduction – Fresnel and Fraunhofer diffraction – Fraunhofer diffraction due to singleslit, double slit and N-slits (qualitative) – Grating spectrum.							
Polarization- Introduction – Types of polarization – Polarization by reflection, refraction and double refraction - Nicol's Prism - Half wave and Quarter wave plates with applications.							
	Unit	–II Lasers ar	nd Fiber optics		10		

Lasers- Introduction – Characteristics of laser – Spontaneous and Stimulated emission of radiation – Einstein's coefficients – Population inversion – Lasing action – Pumping mechanisms – Ruby laser

– He-Ne laser – Applications of lasers.

Fiber optics- Introduction – Principle of optical fiber – Acceptance Angle – Numerical Aperture – Classification of optical fibers based on refractive index profile and modes – Propagation of electromagnetic wave through optical fibers – Propagation Losses (qualitative) – Applications

Unit –III Dielectric and Magnetic Materials

10

10

Dielectric Materials- Introduction – Dielectric polarization – Dielectric polarizability, Susceptibility and Dielectric constant – Types of polarizations: Electronic, Ionic and Orientation polarizations (Qualitative) – Lorentz internal field – Clausius-Mossotti equation.

Magnetic Materials- Introduction –Basic definitions – Origin of permanent magnetic moment – Classification of magnetic materials: Dia, para & Ferro – Hysteresis – Soft and Hard magnetic materials

Unit –IV Semiconductors and Superconductors	
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Semiconductors- Introduction – Classification of crystalline solids – Intrinsic semiconductors – Intrinsic Density of charge carriers- Intrinsic conductivity-Intrinsic Fermi level- Extrinsic semiconductors– p-type and ntype- Drift and diffusion currents – Einstein's equation – Formation of p-n junction diode – Direct and indirect band gap semiconductors – Hall effect – Hall coefficient – Applicationsof Hall effect.

 $\label{eq:superconductors-Introduction-Properties of superconductors-Meissner effect-Type I and TypeII superconductors-BCS theory-Josephson effects (AC and DC) - High T_c superconductors-Applications of superconductors.$

τ	Unit –V Electrostatics and Electromagnetic Waves	8
		0
Floatmostation	Introduction Electric change Coulomb's law Electric filed Ele	atria field due to

Electrostatics -Introduction- Electric charge-Coulomb's law-Electric filed-- Electric field due to linear charge-Gauss' law- statement and its proof- Derivation of Coulomb's law from Gauss law. **Electromagnetic Waves-** Introduction-Divergence and Curl of Electric and Magnetic Fields- Stokes' theorem for curl- Maxwell's Equations (Quantitative)- Electromagnetic wave propagation (Non-conducting medium (dielectric medium)) -Poynting's Theorem.

Course Outcomes:

On completion of this course, the students are able to:

Describe the importance of Interference, Diffraction and Polarization and the engineering applications as well (L2)

 \triangleright

Demonstrate the properties of lasers and to various applications in science and

fibre optics technology (L2)

- Explain the fundamental concepts and theory related to dielectric and magnetic materials (L1)
 Illustrate the functioning of semiconductors in electronic devices (L2)
- \triangleright Discuss the principles and theory related to superconductors and explore their technological applications(L2)
- Explain the electromagnetic wave propagation and its power in non-conducting medium (L2)

Text Books:

- 1. Engineering Physics Dr. M.N. Avadhanulu & Dr. P.G. Kshirsagar, S. Chand and Company
- 2. Engineering Physics B.K. Pandey and S. Chaturvedi, Cengage Learning.
- 3. Applied Physics for Engineers- K.Venkataramanan, R. Raja, M. Sundararajan(Scitech) [3,5]

2014

Reference Books:

- 1. Engineering Physics Shatendra Sharma, Jyotsna Sharma, Pearson Education, 2018
- 2. Engineering Physics K. Thyagarajan, McGraw Hill Publishers
- 3. Engineering Physics Sanjay D. Jain, D. Sahasrambudhe and Girish, University Press
- 4. David J.Griffiths, "Introduction to Electrodynamics"- 4/e, Pearson Education, 2014
- 5. Semiconductor physics and devices- Basic principle Donald A, Neamen, Mc Graw Hill

E-resources:

- https://www.textbooks.com/Catalog/MG5/Applied-Physics.php
- https://edurev.in/courses/9596_Electromagnetic-Theory-Notes--Videos--MCQs--PPTs
- https://libguides.ntu.edu.sg/c.php?g=867756&p=6226561
- https://bookauthority.org/books/best-applied-physics-books
- https://www.electronicsforu.com/resources/16-free-ebooks-on-material-science/2

COMMUNICATIVE ENGLISH									
(Common to all Branches of Engineering)									
Course Code	L:T: P: S	Credits	Exam marks	Exam Duration	Course Type				
22A0013T	3: 0: 0: 0	3	CIE:30 SEE:70	3 Hours	s HSC				
Course Ob	jectives:								
 Facilitate effective listening skills for better comprehension of academic lectures and English spoken by native speakers Help improve speaking skills motivating the learners to participate in activities such as role plays, discussions and structured talks/oral presentations Focus on appropriate reading skills for comprehension of various academic texts and authentic materials Import affective strategies for good writing skills in supporting writing well academic texts. 									
essays, draf Broa appropriate	ting formal lo den the know use in speecl	etters and de redge base of h and writin	esigning well struct of grammatical str	ctured reports uctures and vo	ocabulary and encourage their				
Syllabus			-		Total Hours:48				
Unit - I	On th	he Conduct	of Life: William	Hazlitt	9 Hrs				
Reading: Skimming to get the main idea of a text Scanning to look for specific pieces of information. Reading for Writing: Beginnings and endings of paragraphs - introducing the topic, summarizing the main idea and/or providing a transition to the next paragraph. Grammar and Vocabulary: Parts of Speech, Content words and function words; Word order in sentences; Basic sentence structures; Types of questions - Wh- questions.									
Unit - 11		The Brook:	Alfred Tennyson	1	9Hrs				
Unit - IIThe Brook: Alfred Tennyson9HrsListening: Answering a series of questions about main idea and supporting ideas after listening to audio texts. Speaking: Discussion in pairs/small groups on specific topics followed by short structured talks. Reading: Identifying sequence of ideas; recognizing verbal techniques that help to link the ideas in a paragraph together. Writing: Paragraph writing (specific topics) using suitable cohesive devices; mechanics of writing - punctuation, capital letters. Grammar and Vocabulary: Use of Articles and zero Article Prepositions Punctuation, capital letters Cohesive devices – linkers									

Unit - III	The Death Trap: Saki	11 Hrs						
Listening: I Speaking: Reading: R context clue Writing: Pa Grammar a	Listening for global comprehension and summarizing what Discussing specific topics in pairs or small groups and r eading a text in detail by making basic inferences -recog es; strategies to use text clues for comprehension. ragraph Writing, Summarizing nd Vocabulary: Verbs - Tenses Subject-Verb agreement Direct & Indirect speech	at is listened to. reporting what is discussed nizing and interpreting specific						
Unit - IV	Ponnuthayi – Bama	10 Hrs						
Listening: Making predictions while listening to conversations/ transactional dialogues without video; listening with video. Speaking: Role plays for practice of conversational English in academic contexts (formal and informal) - asking for and giving information/directions. Reading: Read and Interpret graphic Information to reveal trends/patterns/relationships, communicate processes or display complicated data. Writing: Letter Writing: Official Letters/Report Writing Grammar and Vocabulary: Adjectives and Adverbs; Comparing and Contrasting Voice - Active & Passive Voice.								
Unit - V	My Beloved Charioteer- Shasi Deshpande	9 Hrs						
slides Reading: R Writing: W Grammar a (articles, pr Course Ou On comple	Reading for Comprehension Vriting structured essays on specific topics using suitable nd Vocabulary: Identifying and correcting common error epositions, tenses, subject verb agreement) tcomes (CO): tion of this course, student will be able to	claims and evidences. s in grammar and usage						
 Retrie Unde transactiona Apply Analy Evalue of these tex Creations 	eve the knowledge of basic grammatical concepts rstand the context, topic, and pieces of specific informati al dialogues spoken by native speakers of English y grammatical structures to formulate sentences and corre vze discourse markers to speak clearly on a specific topic tate listening /reading texts and to write summaries based ts. eate and develop coherent paragraph interpreting graphic	on from social or ect word forms in informal discussions on global comprehension cal description.						
Textbooks 1) Langua Reference	nge and Life: English Skills for Engineering Students - O Books:	rient Black Swan						
1. 1. Ba 2014. 2. 2. Chas 2nd Edition 3.	ailey, Stephen. Academic Writing: A Handbook for Inter e, Becky Tarver. Pathways: Listening, Speaking and Cri a, 2018. nond Murphy's English Grammar in Use Fourth Edition	rnational Students. Routledge, tical Thinking. Heinley ELT; (2012) E-book						

Raymond Murphy's English Grammar in Use Fourth Edition (2012) E-book Hewings, Martin. Cambridge Academic English (B2). CUP, 2012. 4.

5. Oxford Learners Dictionary, 12th Edition, 2011

6. Norman Lewis Word Power Made Easy- The Complete Handbook for Building a Superior Vocabulary (2014)

Web links:

www.englishclub.com

www.easyworldofenglish.com

www.languageguide.org/english/

www.bbc.co.uk/learningenglish

www.eslpod.com/index.html

		Electroni (Com	c Devices and C mon to ECE, EI	ircuits EE)				
CourseL:T:PCreditsExam.ExamCourse Type								
Code	• • • •		Marks	Duration	700			
22A0401T	3:0:0	3	CIE:30 SFF•70	3 Hours	ESC			
Course Obje	ectives:	1	522.70	1				
To und	erstand the l	basic principles of	of all semiconduct	tor devices.				
\succ To be a	ble to solve	problems related	to diode circuits	, and amplifier ci	rcuits.			
\succ To ana	lyze diode o	circuits, various	biasing and sma	all signal equival	ent circuits of			
amplifiers.	hla ta aamn	are the performe	noo of DITs and	MOSEET				
\succ To desi	on rectifier	circuits and vario	us amplifier circl	MOSFEIS. uits using BITs a	nd MOSEETs			
			Svllabus	uns using DJ15 a				
			Unit –I					
Diodes: Intro	oduction, T	he Ideal Diode	– current voltag	e characteristic,	rectifier, diode logic			
gates, Termi	nal Characte	eristics of Junction	on Diodes– forw	ard bias, reverse	bias, and breakdown			
regions. App	lications: R	Rectifiers – Half	wave, Full wave	rectifier and Br	idge rectifier. Filters -			
Inductor, Car	pacitor, L-se	ection and π -Filte	ers, Zener Diodes	– Zener diode C	haracteristics, Voltage			
shunt regulat	or, Diode a	s switch, Clippir	ng and Clamping	Circuits- limite	r circuit, the clamped			
capacitor, vo	ltage double	er, Special Diode	Types– UJT, S	chottky barrier d	iode, Varactor diode,			
photo diode,	light emittin	g diode(LED), P	roblem Solving.	2				
1	C		Unit –II					
Bipolar Jun	ction Trans	sistors (BJTs):	Physical Operation	on - simplified s	tructure and modes of			
operation,	peration of	the npn, and pn	p transistors: cut	off, active, and	saturation modes, V-I			
Characteristic	cs- of differe	ent configuration	s - graphical rep	resentation of tra	nsistor characteristics,			
dependence	of collector	current on coll	ector voltage, th	ne Early Effect,	Basic BJT Amplifier			
Configuration	ns - Commo	n-Emitter (CE) a	mplifier without	and with emitter	resistance, Common-			
Base (CB) an	nplifier, Cor	nmon-Collector ((CC) amplifier or	Emitter Followe	r, Problem Solving.			
			Unit –III					
MOS Field-	Effect Tra	nsistors (MOS	FETs): Introduc	ction, Device St	ructure and Physical			
Operation –	device struc	cture, operation	with zero gate v	voltage, creating	a channel for current			
flow, operation	ion for diff	erent drain to	source voltages,	the P-channel I	MOSFET, CMOS, V-I			
characteristic	$s-i_D - v_{Ds}$	s characteristics,	$i_D - v_{GS}$ chara	acteristics, finite	output resistance in			
saturation, cl	naracteristics	s of the p-Chan	nel MOSFET, M	IOSFET Circuits	at DC, Applying the			
MOSFET in	Amplifier D	Design – voltage	transfer characte	eristics, biasing th	ne MOSFET to obtain			
linear amplif	fication, the	small signal vo	oltage gain, grap	hical analysis, t	he Q-point. Problem			
solving.								
			Unit –IV					
Biasing of B	JT's & MC	DSFET's: Biasin	g of BJT's – loa	d line, operating	point, fixed bias, self			
bias, voltage	divider bias	s circuits, Bias c	ompensation, Th	ermal runaway, o	condition for Thermal			
stability, Biasing of MOSFET's - Fixed bias, Self bias, Voltage divider bias circuits, Problem								
solving.								
MOODER 9		Omers 4 - N	Unit –V		DC anali- 1.41			
	man Signal	Operation Mo	euels the dc bla	s, separating the	DC analysis and the			
signal analys	is, Small Si	gnai equivalent	circuit models, t	ne transconducta	hogic configurations			
characterizin	ti, Dasic a amplification		co(CS) $constitution$	auons – unree	ith source registered			
common gets	(CC) amplifiers	ifier source fell	ower the omnifi	er frequency rec	nn source resistance,			
solving	(CO) ampl	mer, source ioli	ower, the ampini	ier nequency res	polise, rioulelli			
sorving.								

Text Books:

1. Adel S. Sedra and Kenneth C. Smith, "Microelectronic Circuits – Theory and

Applications", 6th Edition, Oxford Press, 2013.

2. Donald A Neamen, "Electronic Circuits – analysis and design", 3rd Edition, McGraw Hill (India), 2019.

References:

1. J. Milliman and C Halkias, "Integrated electronics", 2nd Edition, Tata McGraw Hill, 1991.

2. R.L. Boylestad and Louis Nashelsky, "Electronic Devices and Circuits," 9th Edition, Pearson, 2006.

Course Outcomes:

After the completion of the course students will able to

> Understand principle of operation, characteristics and applications of Semiconductor diodes.

> Design the diode applications such as rectifiers, clippers and clampers.

> Understand principle of operation, characteristics and applications of Bipolar Junction Transistor and MOSFETs.

- > Design amplifiers using BJTs, and MOSFETs.
- Solve the problems related to Semiconductor diodes, BJTs, and MOSFETs.

Analyze performance of diode applications, biasing circuits of BJTs, MOSFETs and their applications.

		Engin	eering Drawing	_					
(Common to All Engineering Branches)									
Course		Creuits	Marks	Dur	ation	Course Type			
22A0302T	1:0:4	3	CIE:30 SFE:70	3 H	lours	ESC			
Course Ob	jectives:		522.70						
> Brin	g awareness th	nat Engineering I	Drawing is the La	inguage	ofEngine	ers.			
➤ Fam	iliarize how ir	ndustry communi	cates technical in	formatic	on.				
> Tea	ch the practice	s for accuracy an	d clarity in prese	nting the	e technica	l information.			
Dev	elop the engine	eering imaginatio	on essential for su	iccessful	design.	r			
		Syllabus			Total E	lours:50			
Unit-I	Introd	luction to Engin	eering Drawing		10Hrs				
Introduction	to Engineerin	ng Drawing: Princ	ciples of Engineer	ring Dra	wing and	its significance-			
Convention	s in drawing-le	ettering - BIS con	nventions.						
a) Draw t	he Conic sect	tions including I	Ellipse, Parabola	, Hyper	bola, and	the Rectangular			
hyperbola u	sing general n	nethods,	monuclaid						
b) Draw the c) Draw the	ie Cycloid, Ep ne Involutes of	f circle, square, p	entagon, and hex	agon					
•) 214.14		•••••••••••••••••••							
Unit-II	Projec	ctions of points,	lines and planes		10Hrs				
Projections	of points line	s and planes. Pro	viection of points	in any o	wadrant	lines inclined to			
one and bo	th planes, find	ling true lengths.	finding true ind	clination	is, angle i	nade by line.			
Projections	of regular plan	e surfaces using	rotating plane me	ethod.	.,				
Unit-III		Projections o	f Solids		10Hrs				
Projections using auxili	of solids: Pro ary views met	jections of regula hod.	r solids inclined	to one a	nd bothth	e principle planes			
Unit-IV		Sections of	solids		10Hrs				
Sections of pyramid and	solids: Section l cone. True si	n planes and sect hapes of the secti	ional view of rig	ht regula	ar solids-	prism, cylinder,			
Unit-V		Development of	f surfaces		10Hrs				
Development of surfaces: Development of surfaces of right regular solids-prism, cylinder, pyramid, cone and their sectional parts.									
Course Ou	tcomes(CO):								
On complet	ion of this cou	ırse, student will	be able to						
> Dra	w various curv	es applied in eng	ineering. (12)						
> Sho	w projections	of solids and sect	ions graphically.	(12)					
> Dra	w the develop	nent of surfaces of	of solids. (13)						

Textbooks:

1. K.L.Narayana&P.Kannaiah, Engineering Drawing, 3/e, Scitech Publishers, Chennai, 2012.

2. N.D.Bhatt, Engineering Drawing, 53/e, Charotar Publishers, 2016.

ReferenceBooks:

1. Dhanajay A Jolhe, Engineering Drawing, Tata McGraw-Hill, Copy Right, 2009

2. Venugopal, Engineering Drawing and Graphics, 3/e, New Age Publishers, 2000

3. Shah and Rana, Engineering Drawing, 2/e, Pearson Education, 2009

4. K.C.John, Engineering Graphics, 2/e, PHI, 2013

5. Basant Agarwal &C.M.Agarwal, Engineering Drawing, Tata McGraw-Hill, Copy Right, 2008.

COMMUNICATIVE ENGLISH LAB

(Common to all Branches of Engineering)

(Common to an Branches of Engineering)								
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course Type			
22A0014P	0:0:3:0	1.5	CIE:30 SEE:70	3Н	HSC			
Course Ob	jectives	1						
This course	will enable stud	dents to:						
 Students will be exposed to a variety of self instructional, learner friendly modes of language learning Students will learn better pronunciation through sounds, stress, intonation and rhythm Students will be trained to use language effectively to face interviews, group discussions, public speaking Students will be initiated into greater use of the computer in resume preparation, report 								
,]	List of Experi	iments		Total Hours: 48			
1. Phone	etics							
2. Descr	ibing objects/pl	aces/persons						
3. Role	Play or Convers	ational Practic	e					
4. JAM								
5. Etiqu	ettes of Telephor	nic Communio	cation					
6. Grou	p Discussions							
7. Deba	tes							
8. Oral I	Presentations							
9. Interv	views Skills							
10. Read	ing comprehens	ion						
11. E-ma	il Writing							
12. Resu	me Writing							
Course Out	comes:							
On complet	ion of this cours	se, the student	s are able to:					
ListerUnde	ning and repeati rstand the differ	ng the sounds ent aspects of	of English Lang the English lang	guage guage proficien	cy with emphasis on			

- LSRW skills
- > Apply communication skills through various language learning activities
- Analyze the English speech sounds, syllable division, stress, rhythm, intonation for better Listening and Speaking Comprehension.
- Evaluate and exhibit acceptable etiquette essential in social and professional settings
- Create awareness on mother tongue influence and neutralize it in order to Improve fluency in spoken English.

Suggested Software: Walden InfoTech / Young India Films

Reference Books:

1. Bailey, Stephen. Academic writing: A handbook for international students. Routledge, 2014.

2. Chase, Becky Tarver. Pathways: Listening, Speaking and Critical Thinking. Heinley ELT; 2nd Edition, 2018.

3. Skillful Level 2 Reading & Writing Student's Book Pack (B1) Macmillan Educational.

4. Hewings, Martin. Cambridge Academic English (B2). CUP, 2012.

5. A Textbook of English Phonetics for Indian Students by T. Balasubramanyam

Online Learning Resources/Virtual Labs:

www.esl-lab.com

www.englishmedialab.com

www.englishinteractive.net

APPLIED PHYSICS LAB

(Common to ECE, EEE)									
Course Code	L:T:P:S	Credits	Exam Marks	Exam Duration	Course 7	Гуре			
22A0008P	0:0:3:0	1.5	CIE:30 SEE:70	3Н		BSC			
		(Course Object	ves:					
This course w	ill enable stude	ents to:							
 Understands the concepts of interference, diffraction and their applications. Understand the role of optical fiber parameters in communication. Recognize the importance of energy gap in the study of conductivity and Hall Effect in a semiconductor. Illustrates the magnetic and materials applications. Apply the principles of semiconductors in various electronic devices 									
	SyllabusTotal Hours: 48								
Note: In the for virtual mode	ollowing list, ou	it of 12 experi	iments, any 2 ex	xperiments must	be performe	d in a			
		L	ist of Experim	ents					
1. Determine	the thickness of	of the wire us	ing wedge shap	be method					
2. Determinat	tion of the radi	us of curvatu	re of the lens b	y Newton's ring	method				
3. Determina	tion of waveler	ngth by plane	diffraction gra	ting method					
4. Determinat	tion of dispersi	ve power of p	orism.						
5. Determina	tion of waveler	ngth of LASE	R light using c	liffraction grating	5.				
6. Determinat	tion of particle	size using LA	ASER.						
7. To determinangle	ine the numeric	cal aperture o	f a given optica	l fiber and hence	to find itsac	cceptance			
8. Magnetic f	field along the	axis of a circu	ılar coil carryin	g current –Stewa	art Gee's m	ethod.			
9. Studythe v	variation of B v	ersus H by m	agnetizing the	magnetic materi	al (B-H curv	ve)			
10. To determ	ine the resistiv	ity of semicor	nductor by Fou	r probe method					
11. To determ	ine the energy	gap of a semi	iconductor						
12. Determina HallEffect.	tion of Hall vo	ltage and Hal	l coefficient of	a given semicon	ductor using	5			

Course Outcomes:

On completion of this course, the students are able to:

 \triangleright Determine the radius of a curvature and / or thickness of thin wire using microscope with the helpof interference concept (L2)

 \succ Evaluate the wavelength of various colors of grating and also dispersive power of prism by spectrometer using the principle of diffraction (L2)

 \triangleright Evaluate wavelength of light source and particle size with He-Ne laser using the principle of diffraction Estimate the numerical aperture of a given optical fiber and hence to find its acceptance angle (L2)

Estimate the dielectric constant of a given material (L2)

 \succ Examine the hysteresis loss of the magnetic material by B- H curve and Estimate the magnetic field of a circular coil carrying current along the axis (L2)

> Measure the type of conductivity ,hall voltage and hall coefficient of a given semiconductor usinghall effect and also measure the energy band gap of a given semiconductor material (L2)

Text Books:

1. Engineering Practical Physics B Mallick S Panigrahi, 1st, Edition, Cengage Learning Publishers

2. A Text book of Engineering Physics Practical, Dr. Ruby Das, Dr. Rajesh Kumar, C. S. Robinson, Prashant Kumar Sah, UNIVERSITY SCIENCE PRESS (An Imprint of Laxmi Publications Pvt. Ltd.)

Reference Books:

1. S. Balasubramanian, M.N. Srinivasan "A Text book of Practical Physics"- S ChandPublishers, 2017

E-resources:

http://vlab.amrita.edu/index.php -Virtual Labs, Amrita University

https://www.scribd.com/doc/81569075/Physics-Lab-Manual

http://www.mlritm.ac.in/assets/img/Lab%20manual%20Physics.pdf

https://bmsit.ac.in/public/assets/pdf/physics/studymaterial/Physics%20lab%20manual_cbcs%20%20-%20kavichintu.pdf

ELECTRONIC DEVICES AND CIRCUITS LAB									
Course	L:T:P	Credits	EXAM.	Exam	Course				
Code			Marks	Duration	Туре				
22A0402P	0:0:3	1.5	CIE:30 SEE:70	3 Hours	PC				
Course Obje	ctives:								
> To verif	y the theoretical	concepts practica	lly from all the e	experiments.					
\rightarrow 10 analy	yse the character	stics of Diodes, E	3JI, MOSFEI. iven specificatio	nns					
\succ To Mod	el the electronic	circuits using tool	ls such as PSPIC	CE/Multisim.					
		Sylla	abus						
LIST OF EX	PERIMENTS:	(Conduct all exp	eriments).						
Note: All the	experiments sha	all be implement	ed using both H	lardware and Sol	ftware.				
1. Design	a half wave rec	tifter with and w	ad and ditions	r the given specific	fications, and				
relevant grant	nts experimental	ily for different fo	bad conditions, a	liso Calculate ripp	le factor with				
2 Design	a full wave rec	tifier with and w	ithout filters fo	r the given speci	fications and				
2. Design	a full wave feel ults experimental	lly for different lo	ad conditions	lso Calculate rinn	le factor with				
relevant grant	nes experimental	ity for different to	ad conditions, a		ie lactor with				
3. Verify t	he operation of	various clipping	and clamper ci	rcuits using PN in	unction diode				
experimentally	v.	turious empring							
4. Design a	a voltage regulate	or using Zener die	de and verify lo	ad regulation char	acteristics.				
5. Analyze	the input and o	output characteris	tics of BJT in (Common Emitter	configuration				
experimentall	y.	-			-				
6. Analyze	the input and	output characteri	istics of BJT ir	n Common Base	configuration				
experimentall	у.								
7. Design	voltage- divider l	bias/self-bias circu	it using BJT an	d verify experiment	ntally.				
8. Design a	a small signal an	nplifier using BJT	C (common emit	ter) for the given	specifications				
also calculate	Bandwidth.								
9. Analyze	e the output an	nd transfer chara	acteristics of N	AOSFET in Cor	nmon Source				
Configuration	experimentally.		1	. 11					
10. Design s	self-bias circuit u	sing MOSFET an	id verify experin	nentally.					
12 Design	a small signal	switch using CM	OSFEI/JFEI/D	JT experimentally	c. For the given				
specifications	a sinali signal	amplifier using	MOSPET (CC	fillition source) i	of the given				
Tools / Fauin	ment Required	• Software Tool li	ke Multisim/ Ps	nice or Equivalent					
DC Power su	polies. Multi me	ters. DC Ammete	ers. DC Voltmet	ters. AC Voltmete	, ers. CROs. all				
the required a	ctive devices.	,	,	,	, ,				
Course Outco	omes:								
After the com	pletion of the cou	urse students will	able to						
 Underst Design t 	and the operation	tions like Rectifie	ers. Clippers and	TORIC devices. Clampers for the	given				
specifications			, enppois un		0				
Analyze	the Characterist	ics of Diodes, BJ	Γs, MOSFETs.						
Design I	BJT based ampli	fiers for the given	specifications.						
 Design I Simulat 	NOSFET based	amplifiers for the	given specificat	1011S F /Multisim					